



Laboratorij za načrtovanje integriranih vezij



**FE**

UNIVERZA V LJUBLJANI  
Fakulteta za elektrotehniko

## **Linearna elektronska vezja**

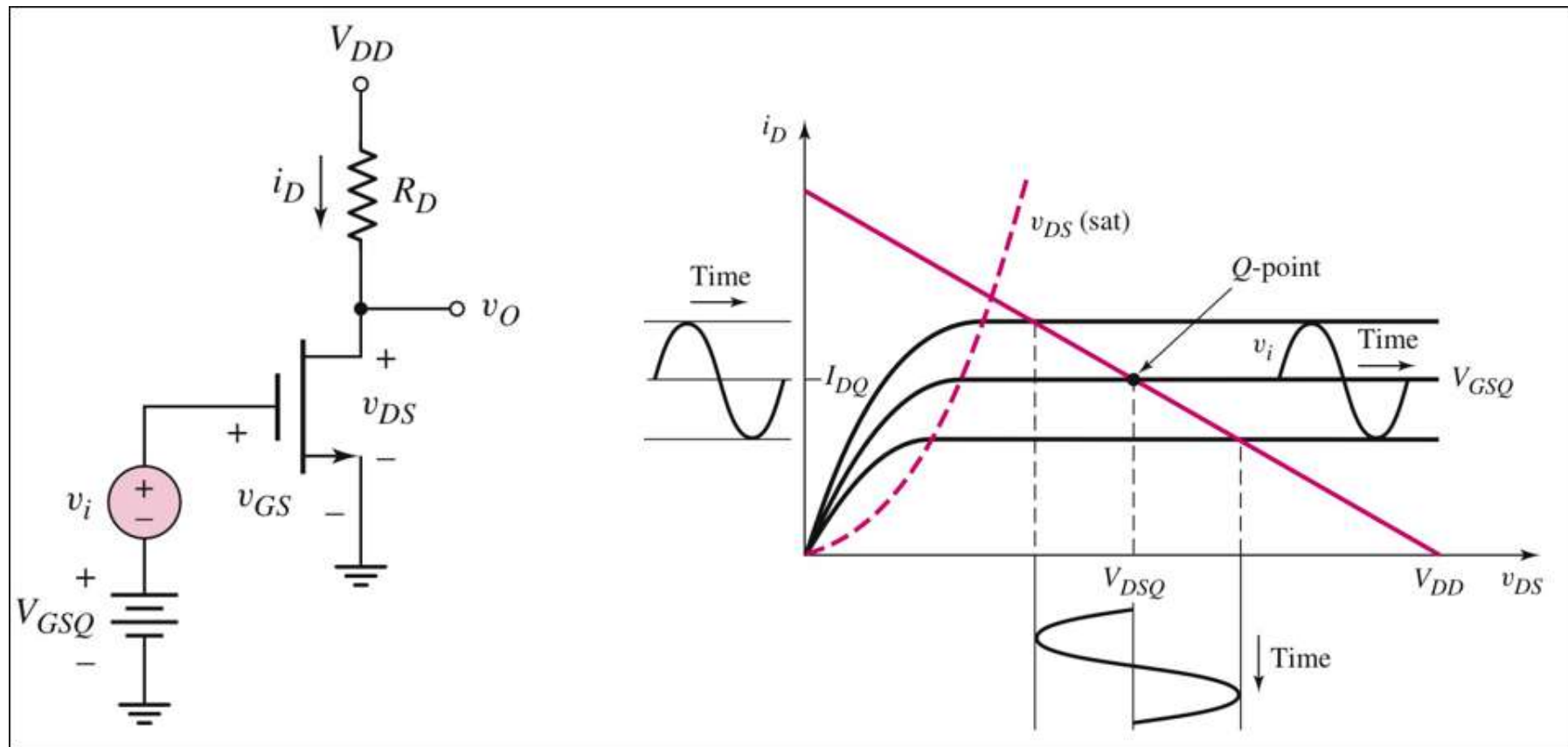
MOSFET Ojačevalnik

## In this chapter, we will:

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- ▶ Investigate a single-transistor circuit that can amplify a small, time-varying input signal
  - ▶ Develop small-signal models that are used in the analysis of linear amplifiers
- ▶ Discuss and compare the three basic transistor amplifier configurations.
  - ▶ Analyze the common-source amplifier.
  - ▶ Analyze the source-follower amplifier.
  - ▶ Analyze the common-gate amplifier.
- ▶ Analyze multitransistor or multistage amplifiers.

# NMOS Common-Source Circuit



## MOS Transistor Small-Signal Parameters

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Values depends on Q-point

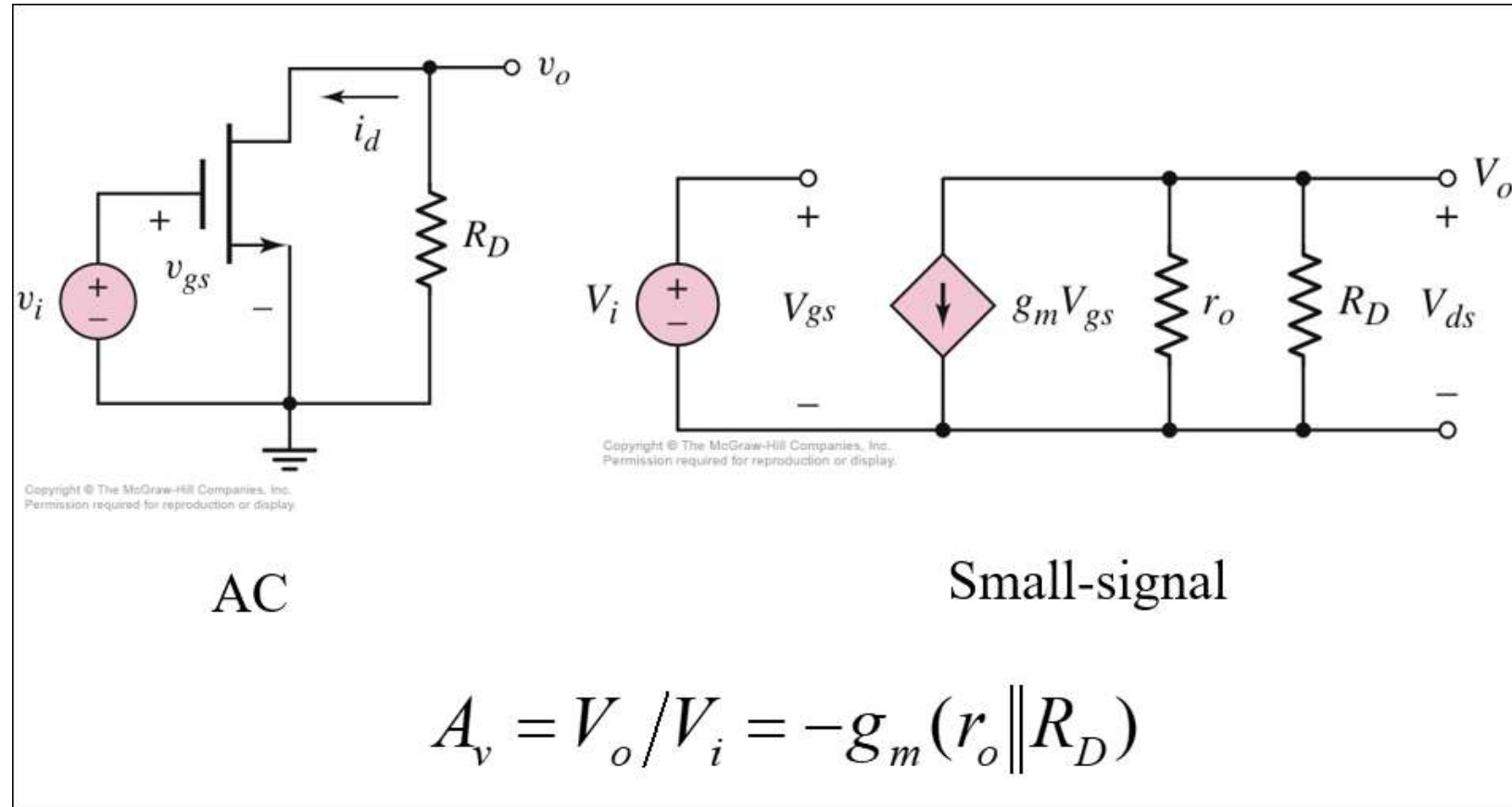
$$g_m = \frac{\partial i_D}{\partial v_{GS}} = \frac{i_d}{v_{gs}}$$

$$g_m = 2K_n (V_{GSQ} - V_{TN}) = 2\sqrt{K_n I_{DQ}}$$

$$r_o = \left( \frac{\partial i_D}{\partial v_{DS}} \right)^{-1}$$

$$r_o = [\lambda K_n (V_{GSQ} - V_{TN})^2]^{-1} \cong [\lambda I_{DQ}]^{-1}$$

# NMOS Common-Source Circuit



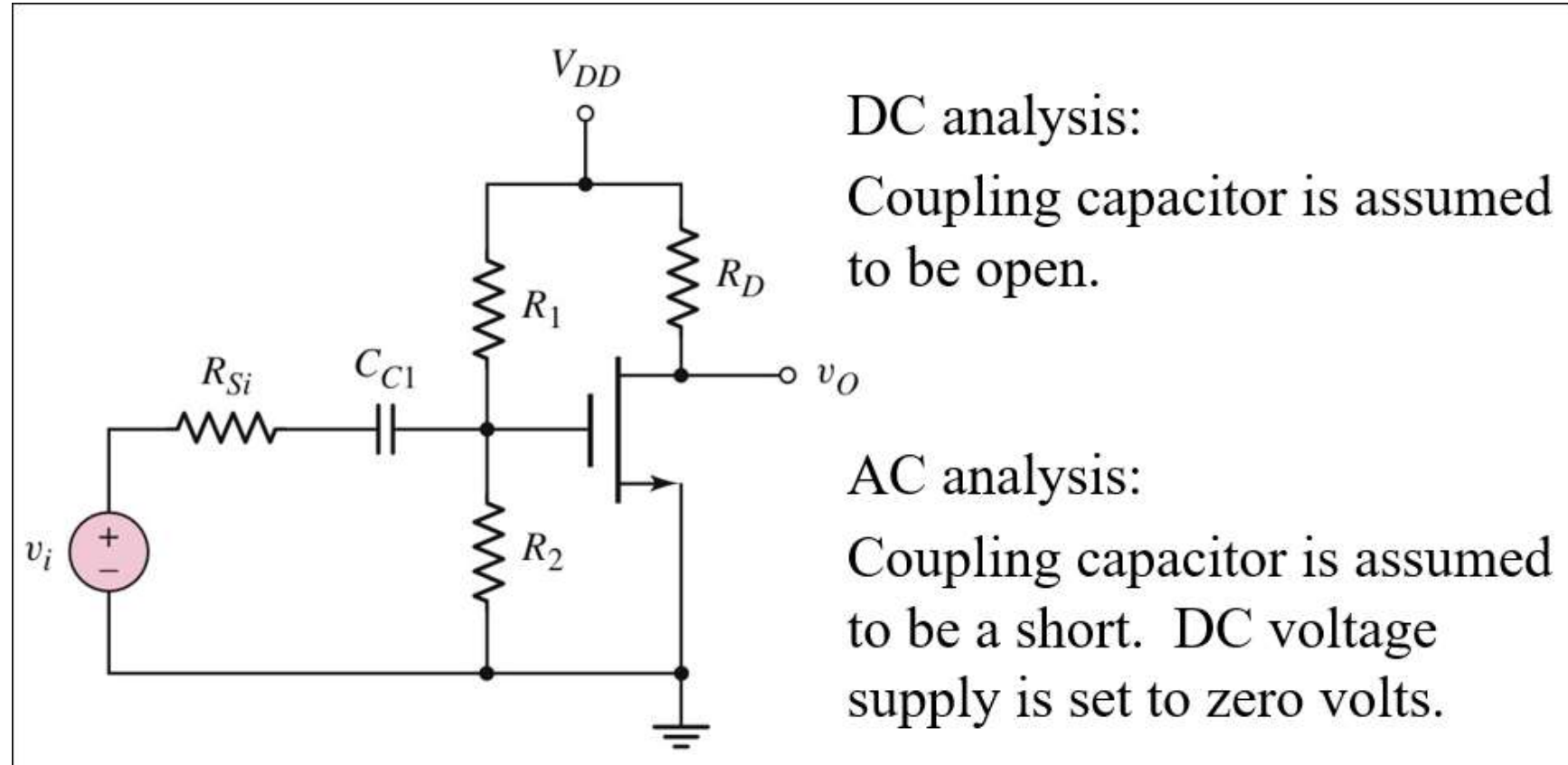
## Problem Solvning Techniques

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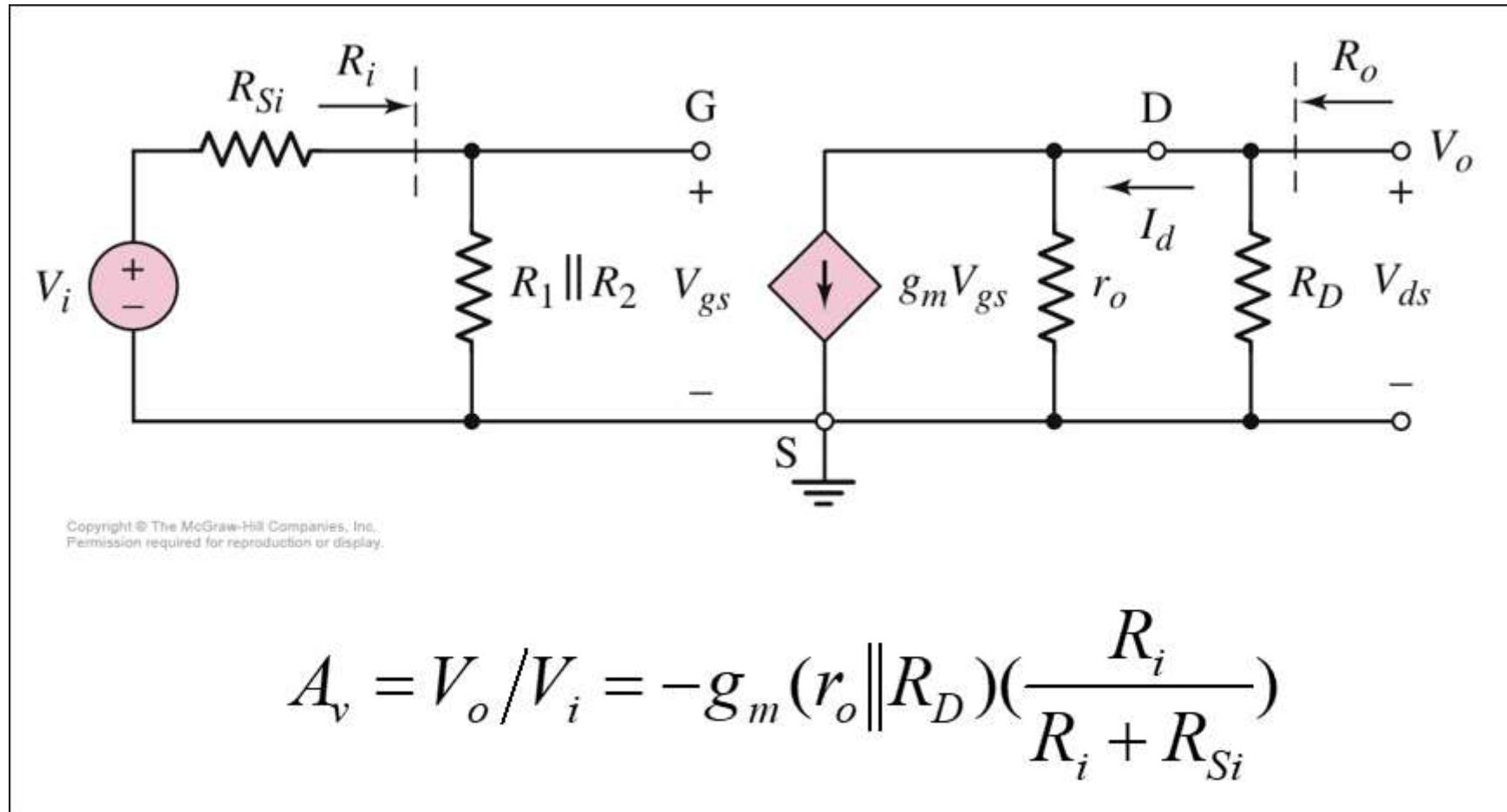
1. Analyze circuit with only the dc sources to find quiescent solution.
  - Transistor must be biased in saturation region for linear amplifier.
2. Replace elements with small-signal model.
3. Analyze small-signal equivalent circuit, setting dc sources to zero, to produce the circuit to the time-varying input signals only.

# NMOS Common-Source Configuration

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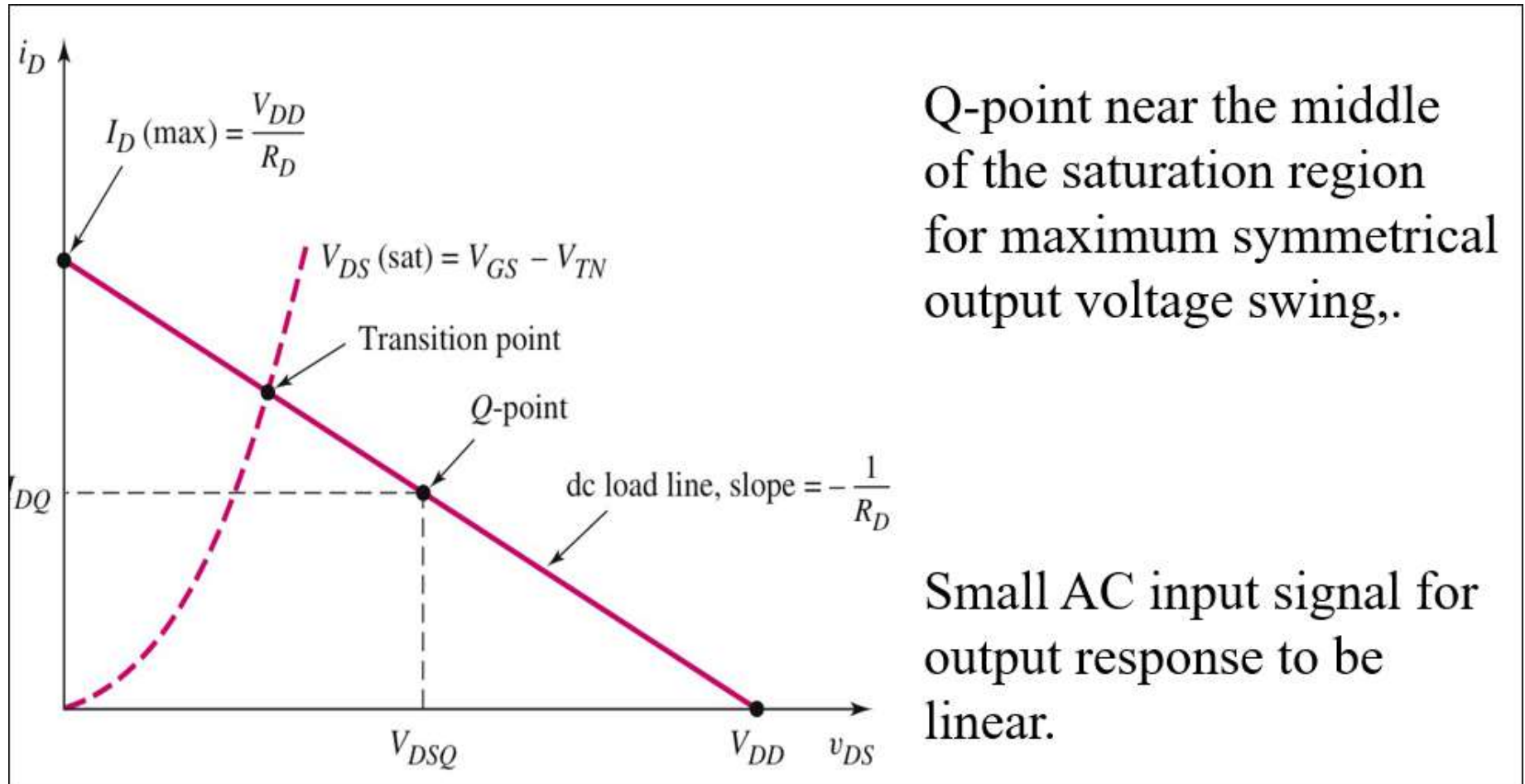


## Small-Signal Equivalent Circuit



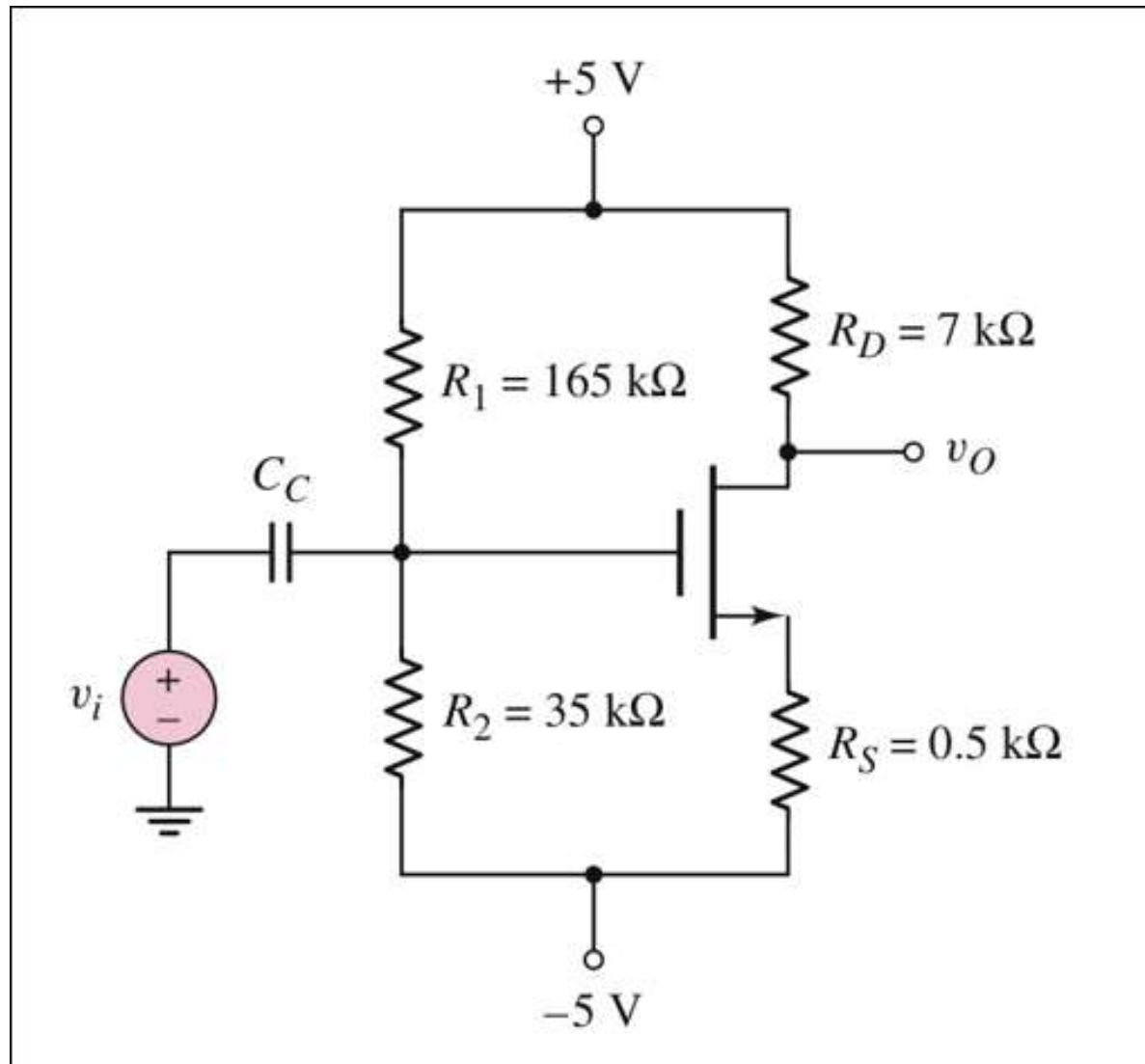


## DC Load Line



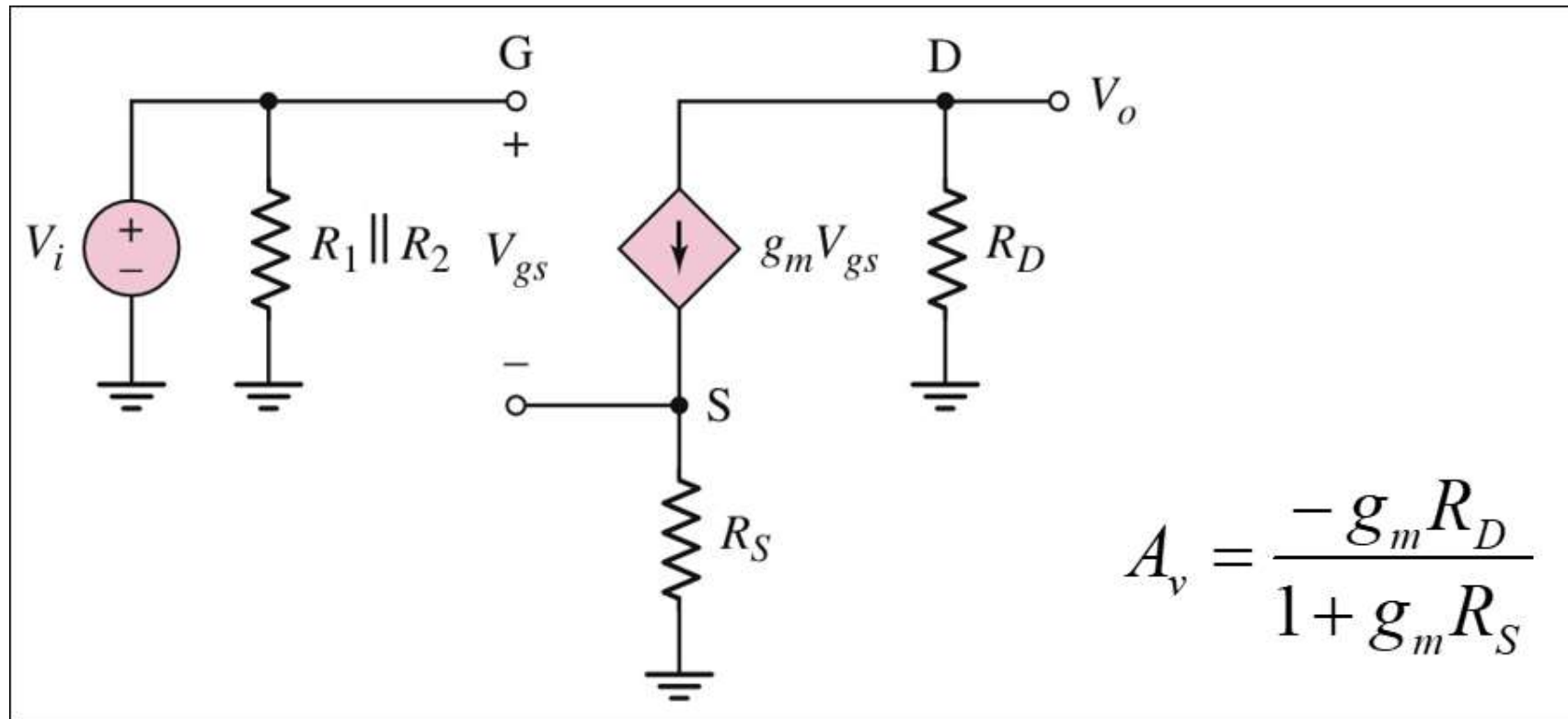
## Common-Source Amplifier with Source Register

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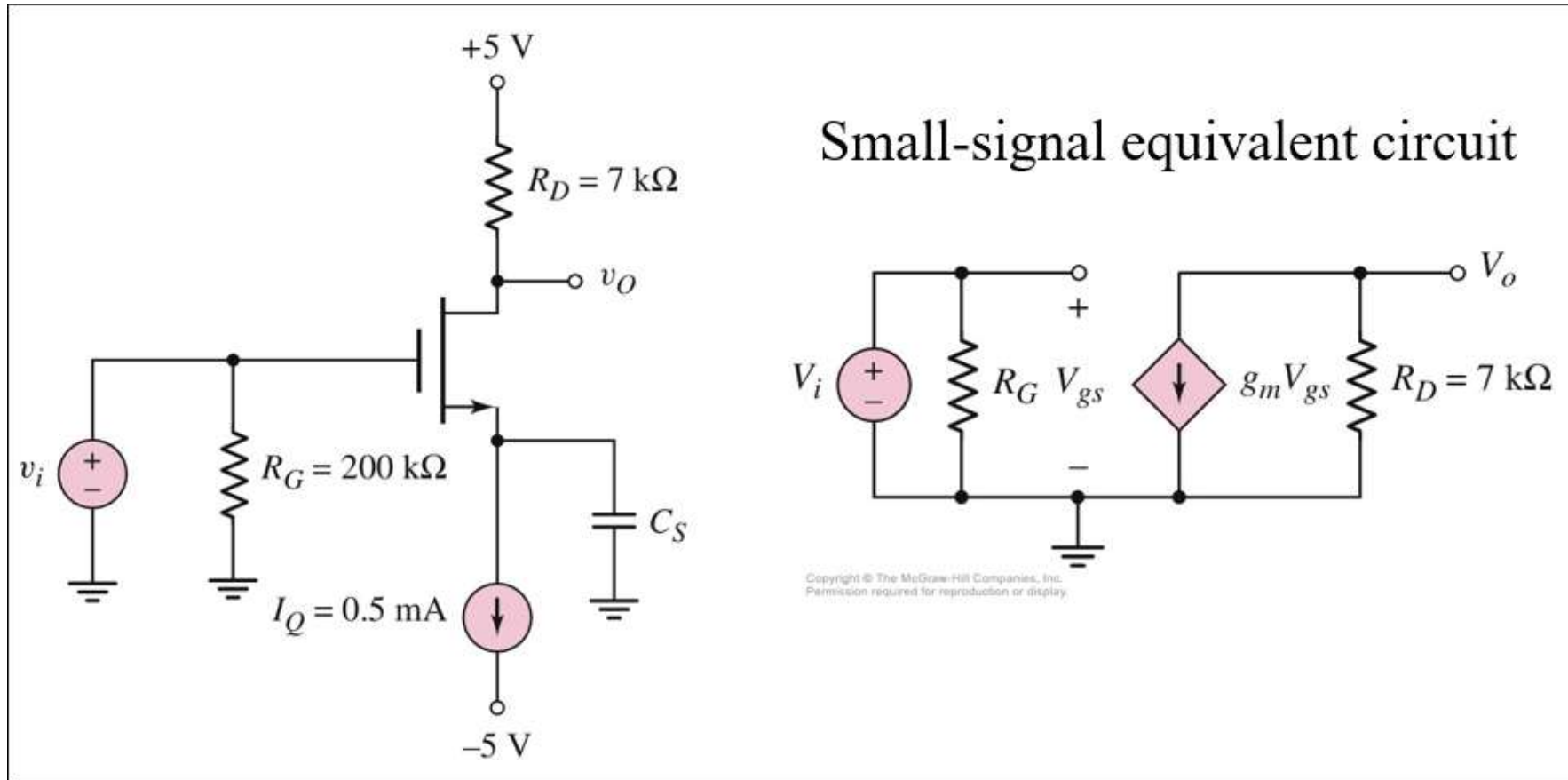


## S-S E-C for C-S Amplifier with Source Register

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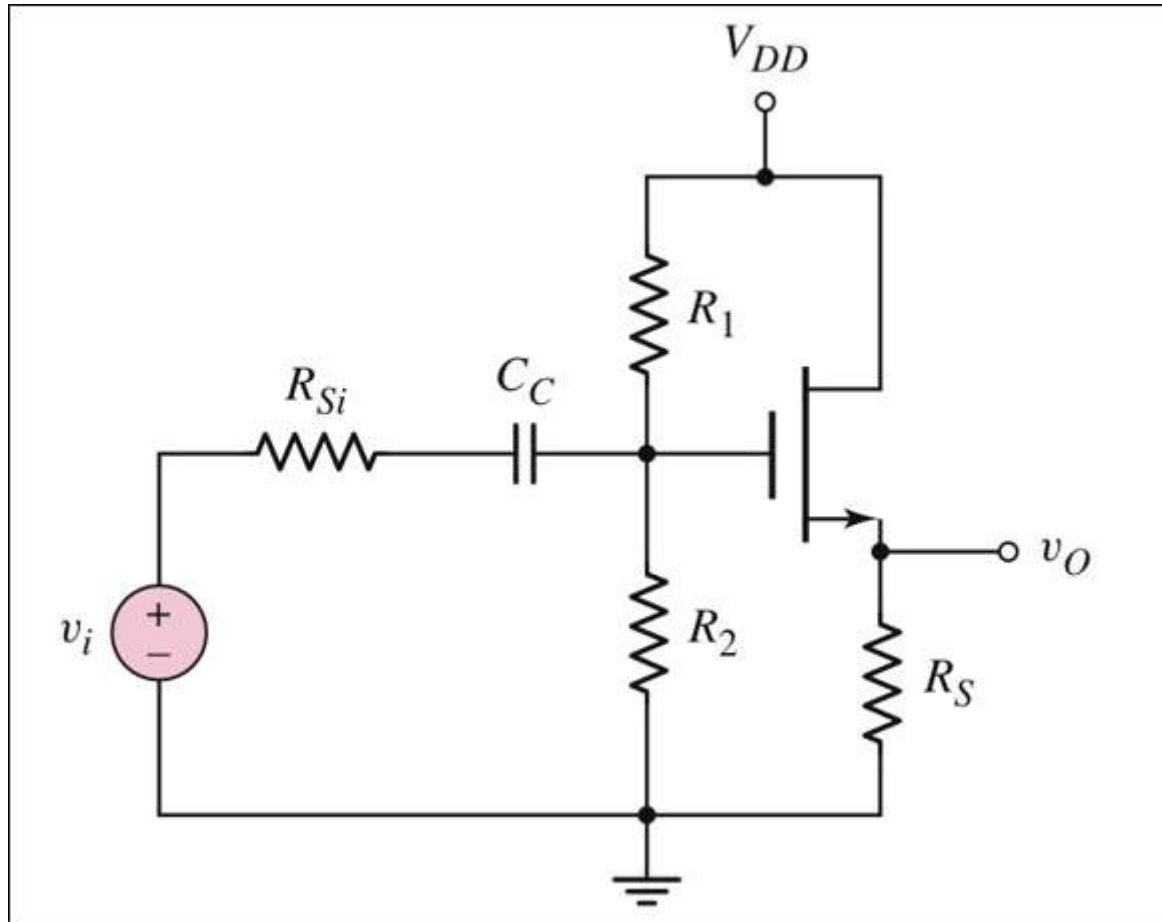


# C-S Amplifier with Bypass Capacitor

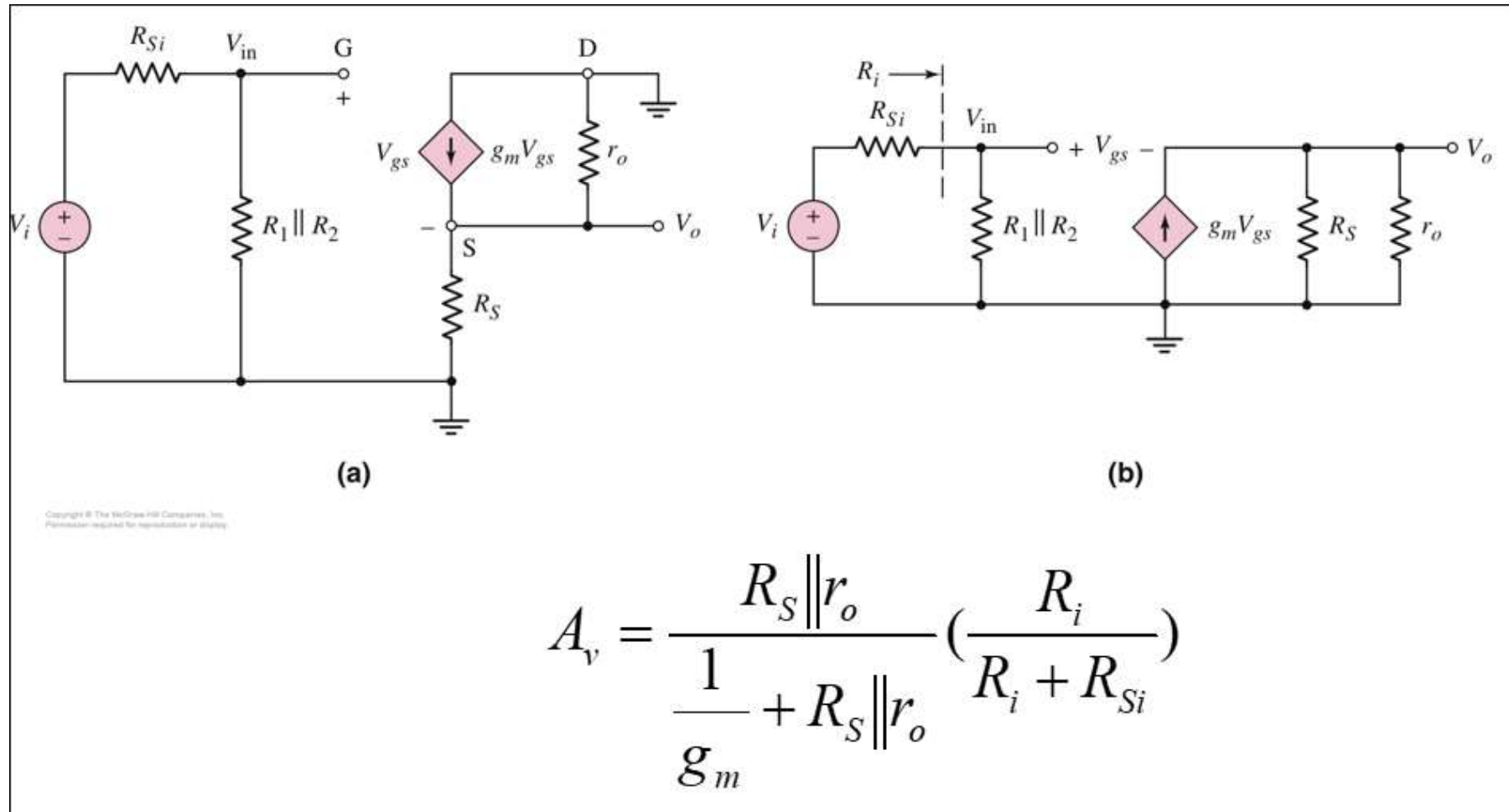


## Common-Drain Configuration (Source Follower)

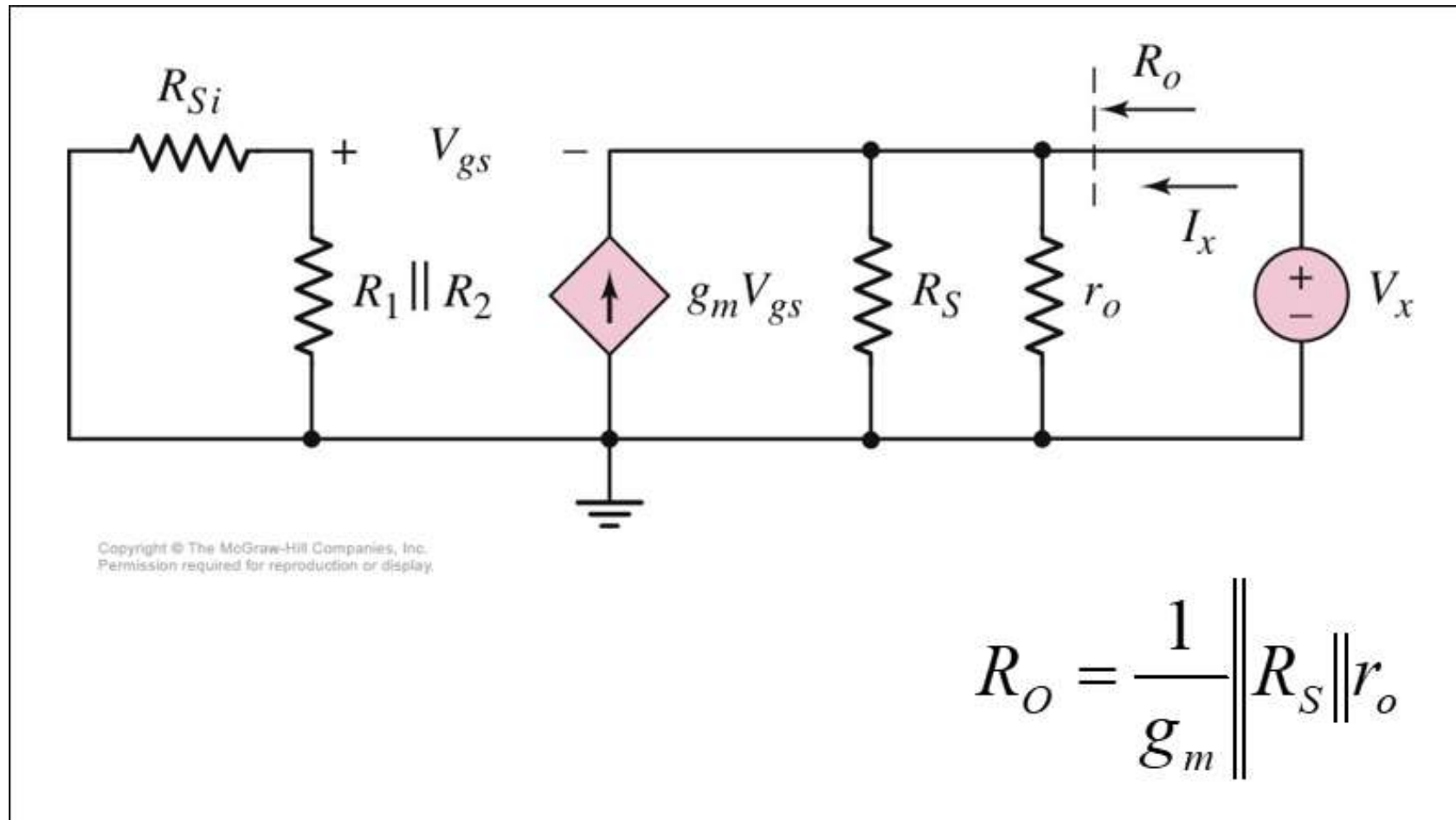
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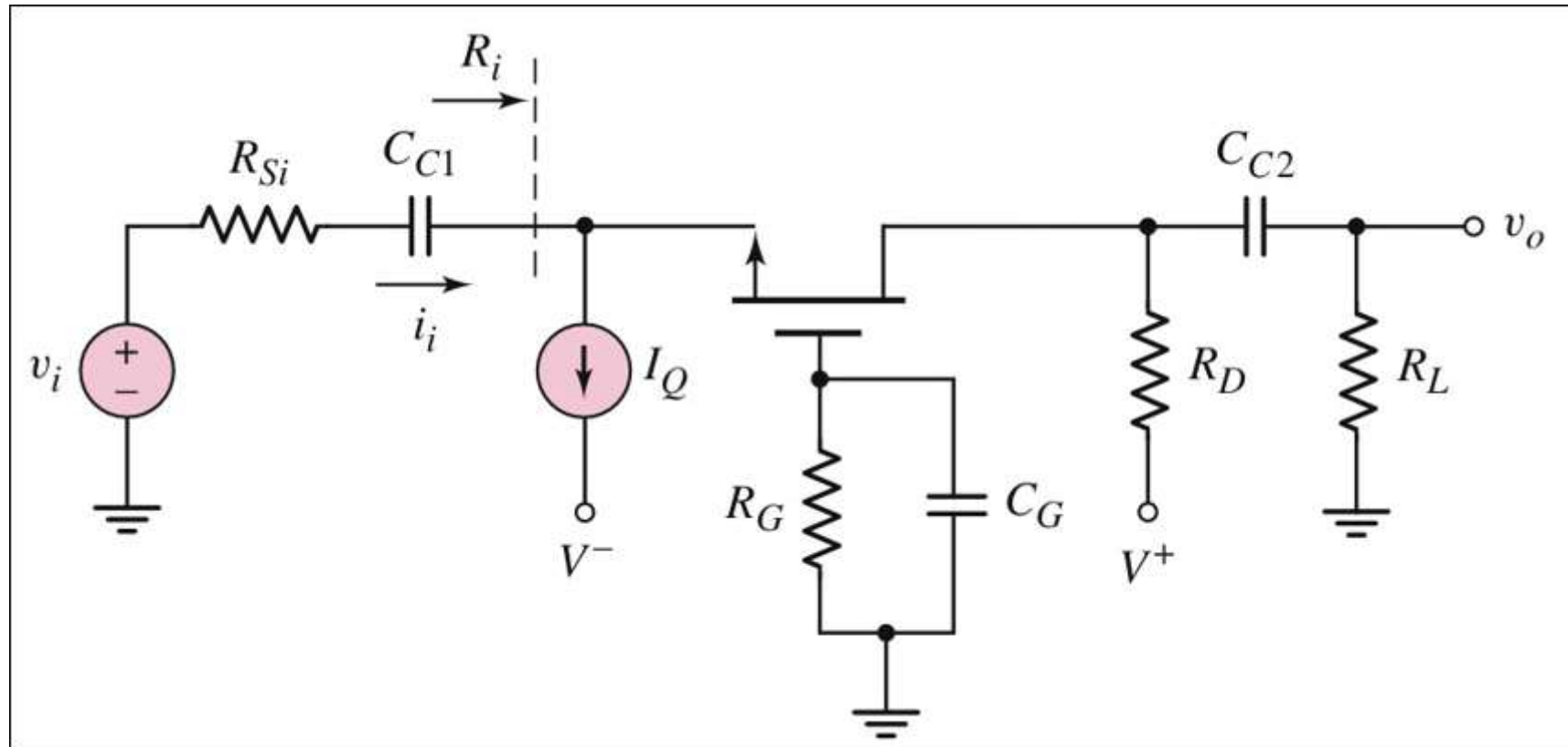
# S-S E-C for Source Follower



## Determining Output Impedance of Source Follower

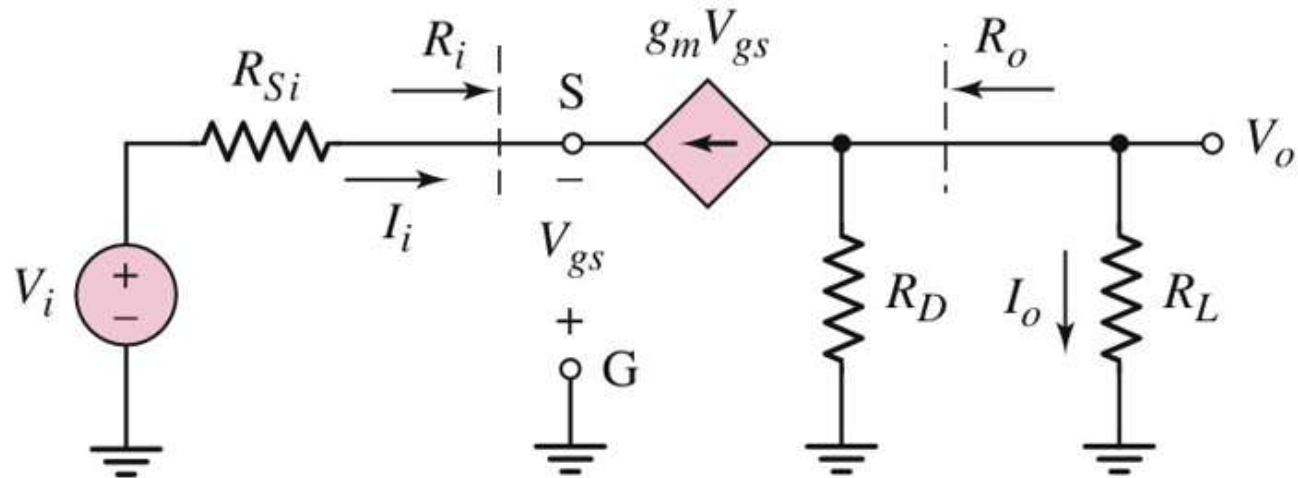


# Common-Gate Configuration





## S-S E-C for Common-Gate



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$$A_v = \frac{g_m (R_D \parallel R_L)}{1 + g_m R_{Si}}$$

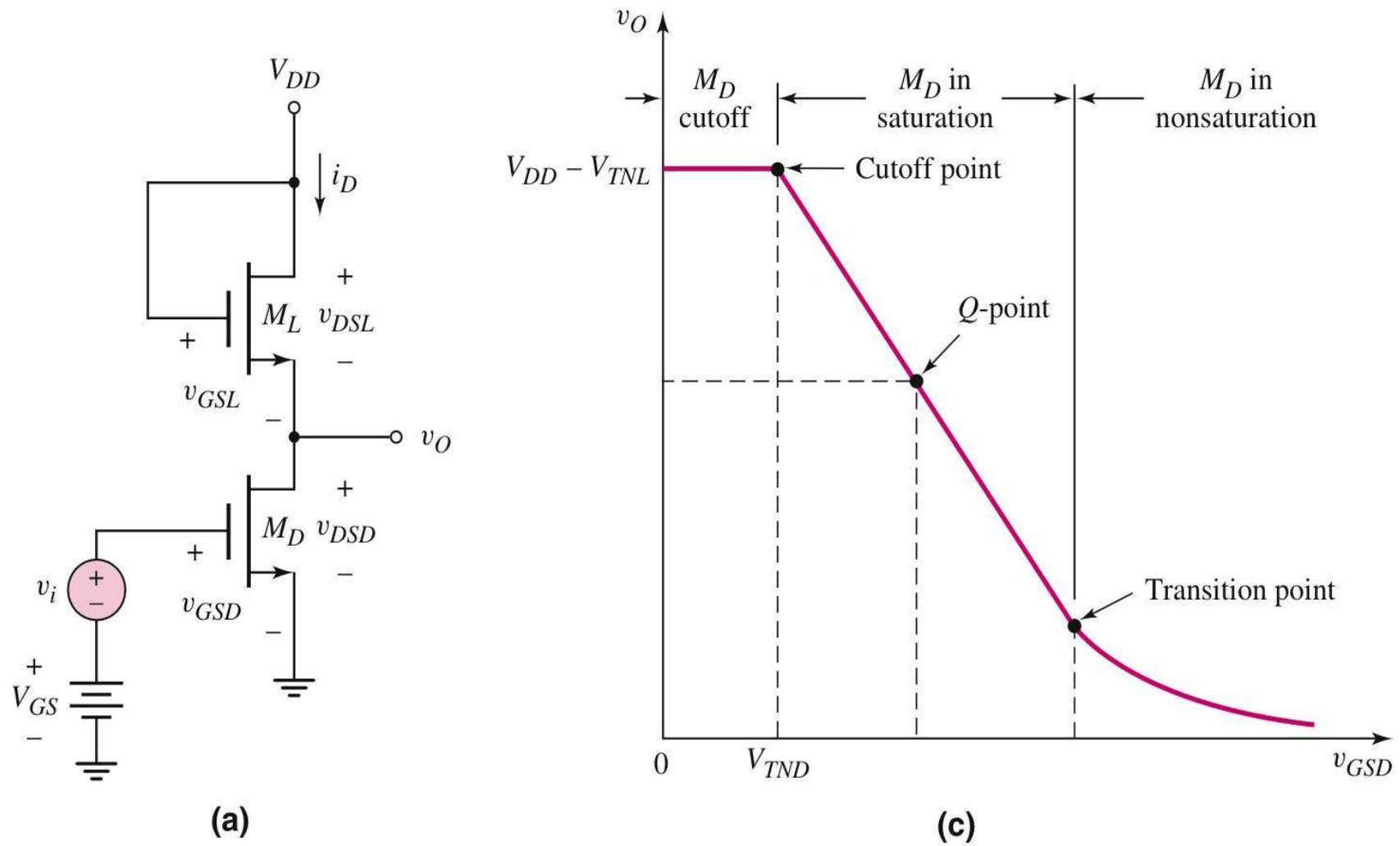
$$A_i = \frac{I_o}{I_i} = \left( \frac{R_D}{R_D + R_L} \right) \left( \frac{g_m R_{Si}}{1 + g_m R_{Si}} \right)$$

## Comparison of 3 Basic Amplifiers

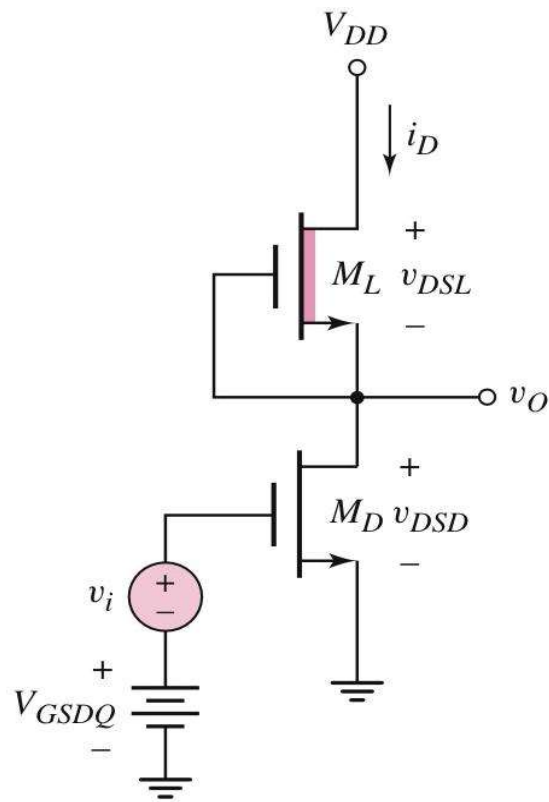
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Configuration	Voltage Gain	Current Gain	Input Resistance	Output Resistance
Common Source	$ A_v  > 1$	—	$R_{TH}$	Moderate to high
Source Follower	$A_v \approx 1$	—	$R_{TH}$	Low
Common Gate	$A_v > 1$	$A_i \approx 1$	Low	Moderate to high

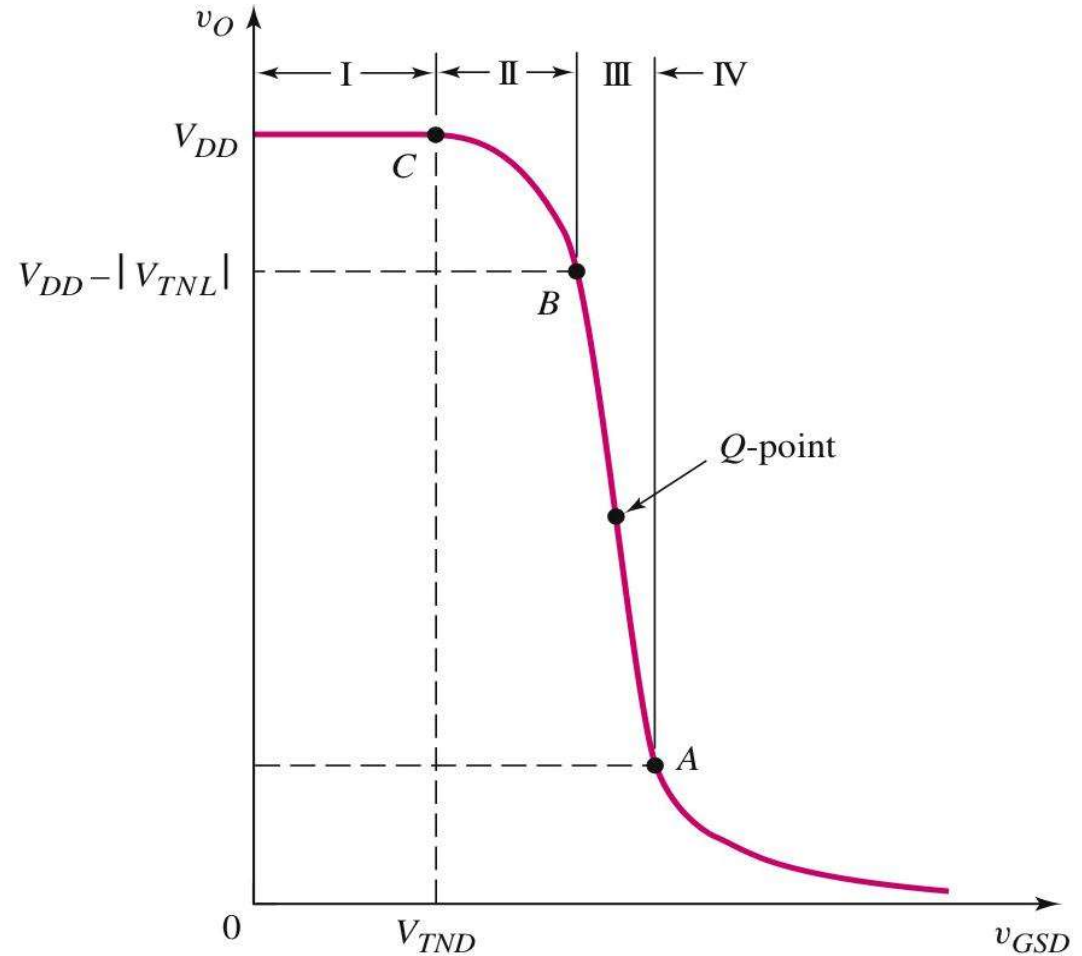
# NMOS Amplifier with Enhancement Load Device



# NMOS Amplifier with Depletion Load Device

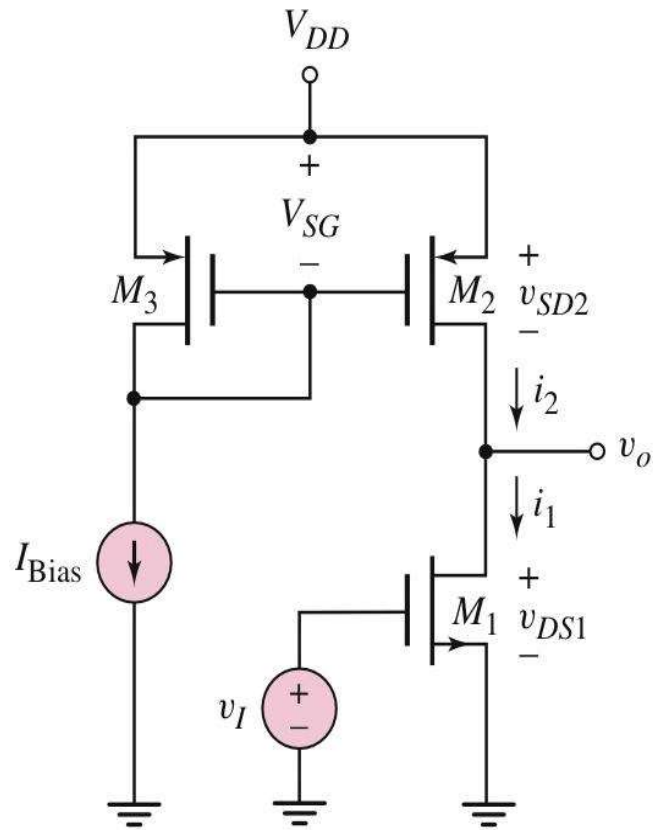


(a)

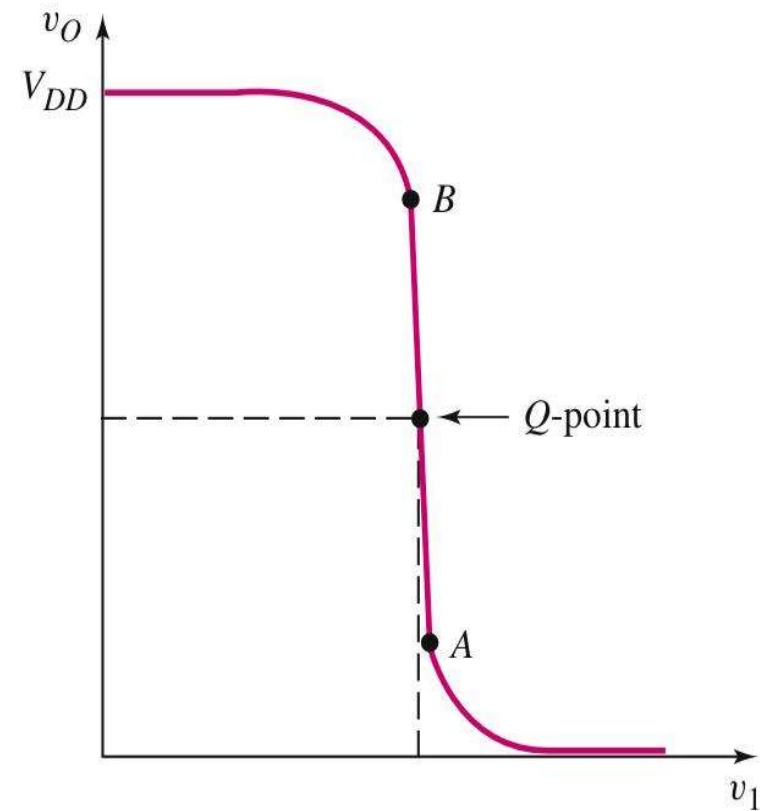


(c)

# CMOS Common-Source Amplifier

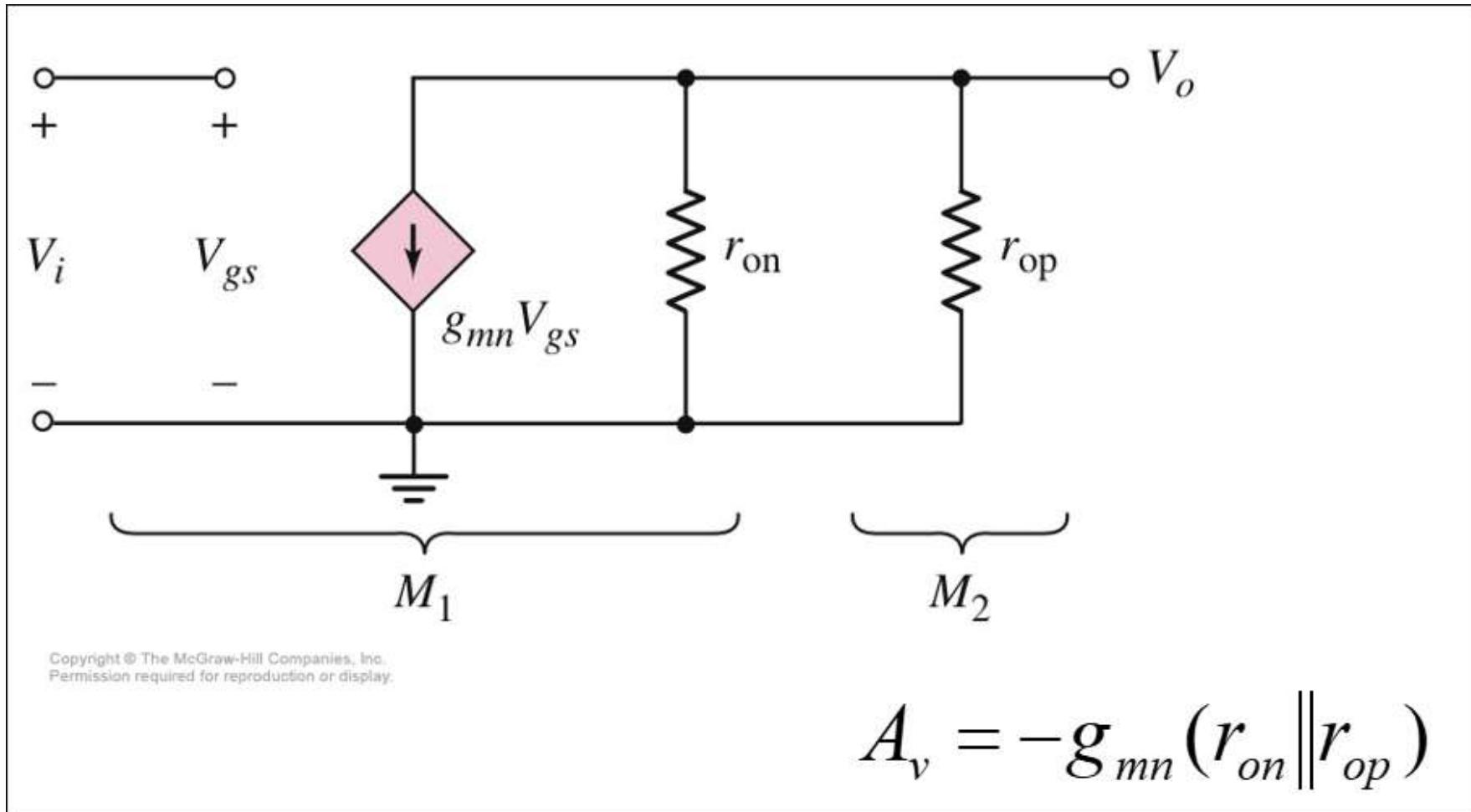


(a)

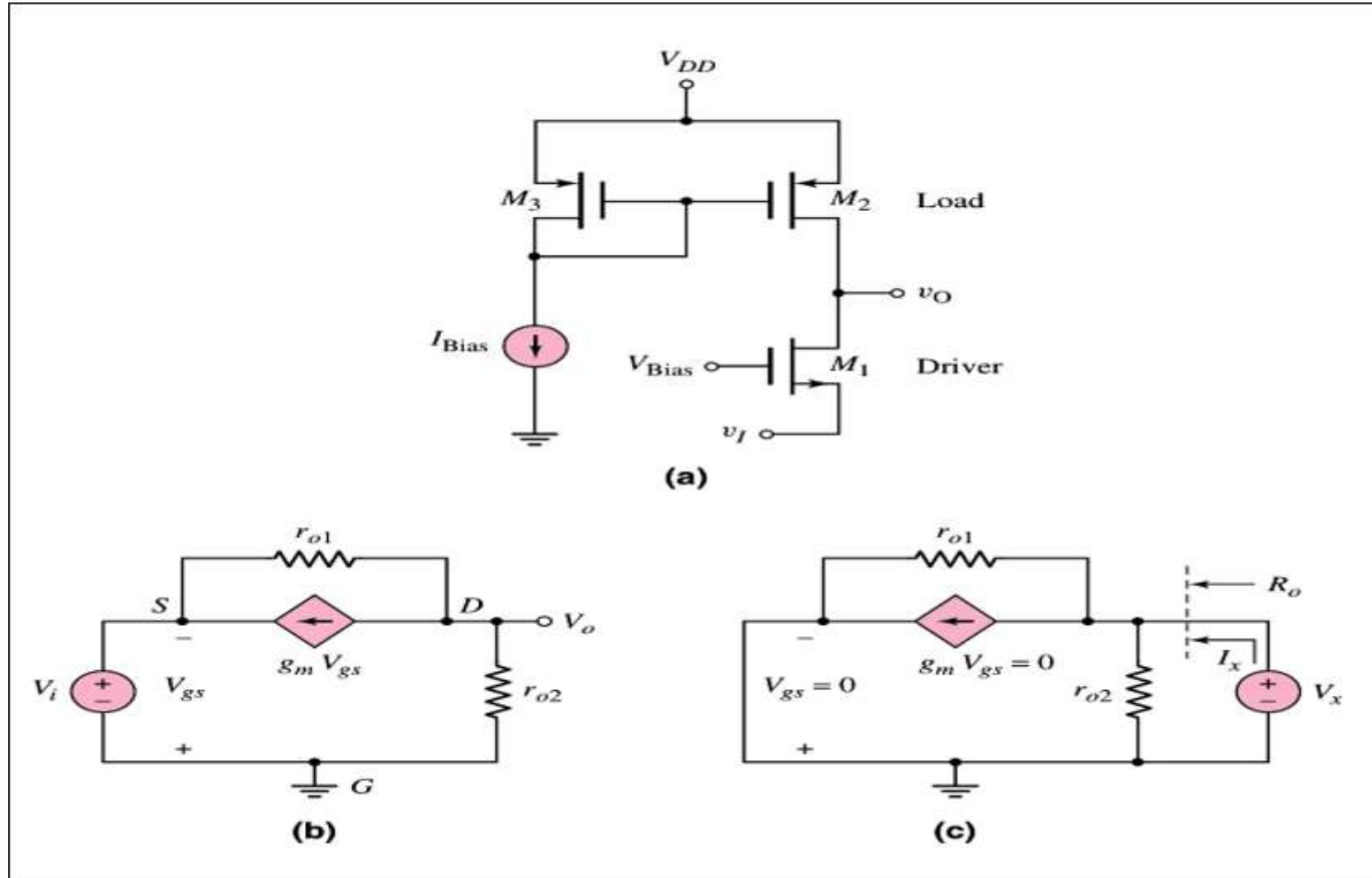


(d)

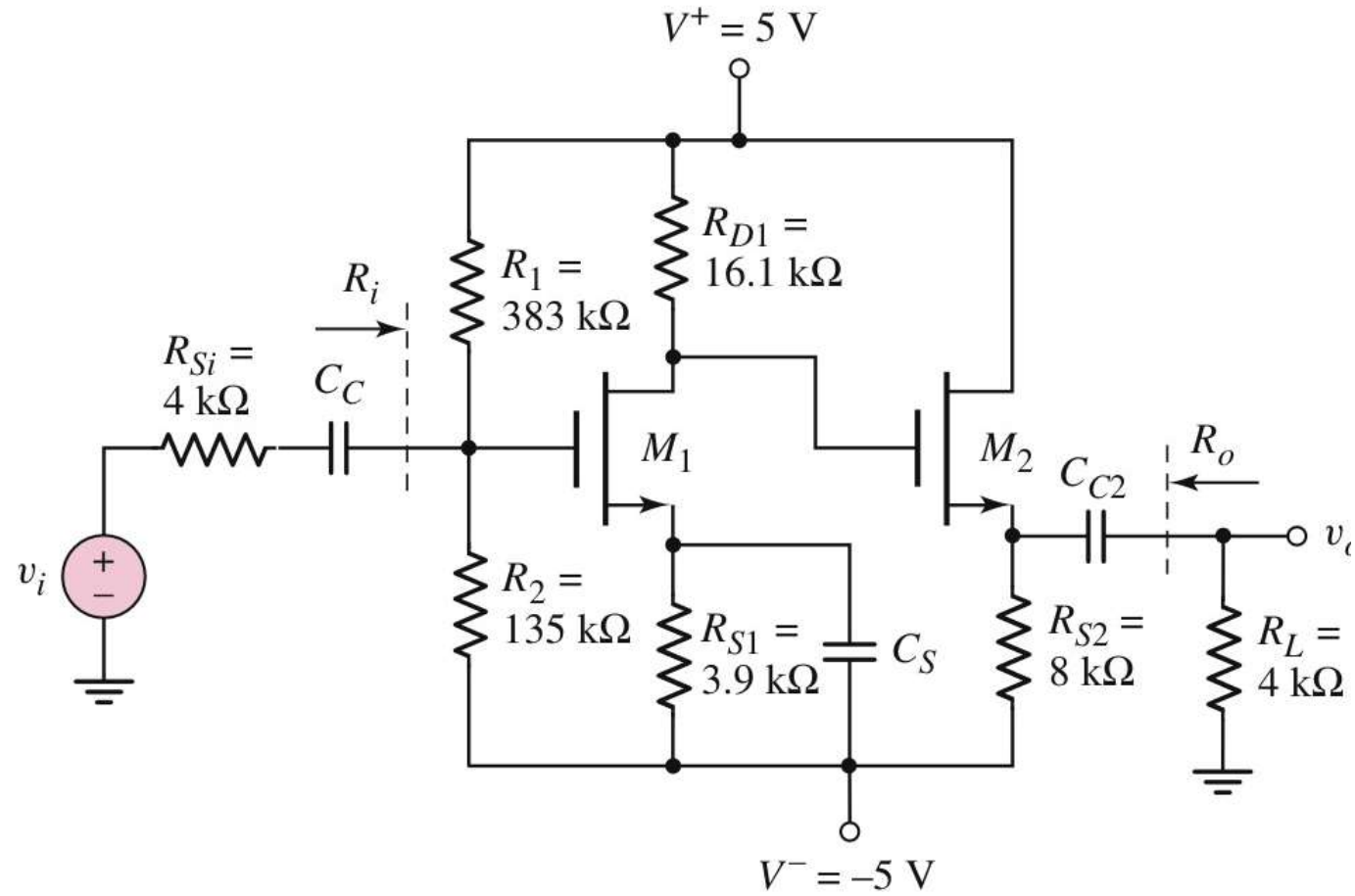
# S-S E-C for CMOS Common Source



# CMOS Common Gate

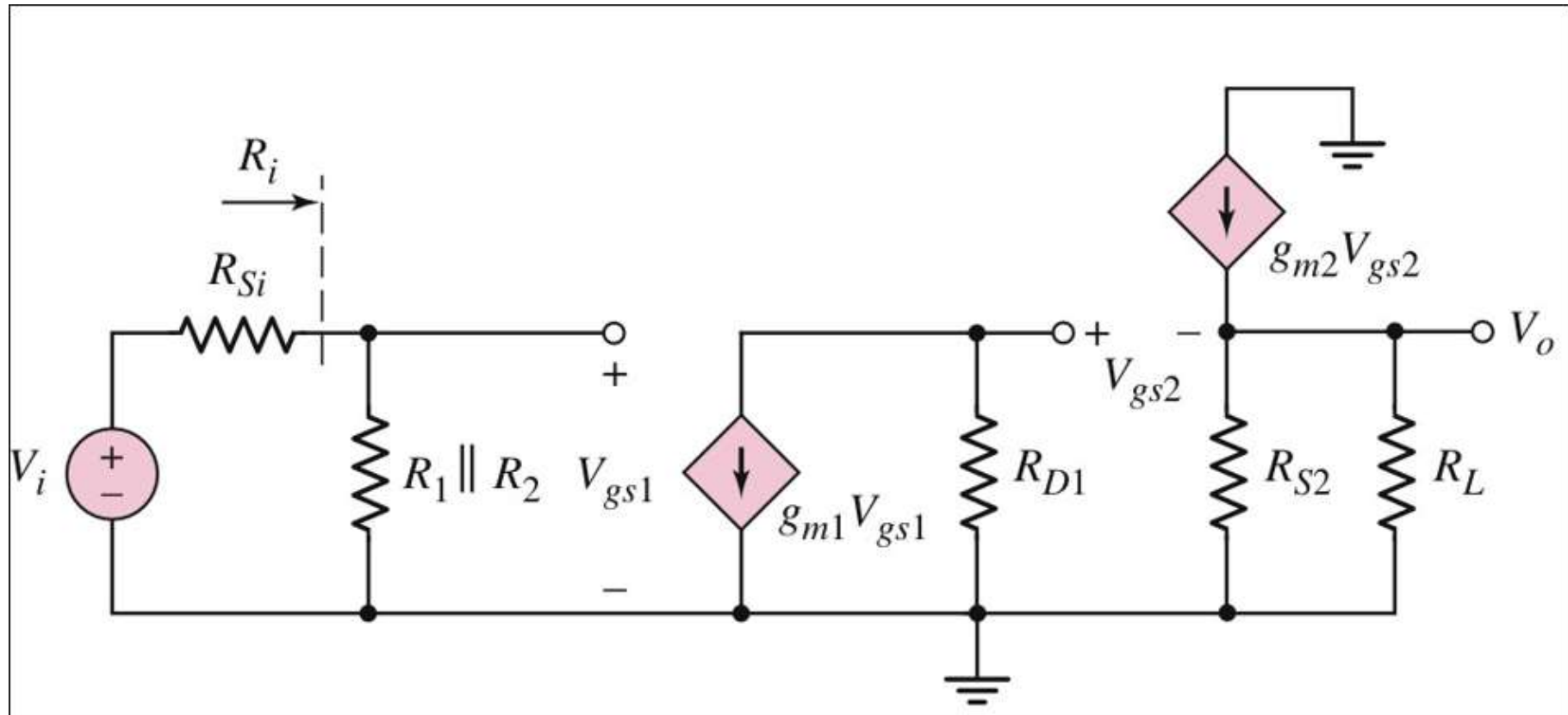


# Cascade Circuit





## S-S E-C for Cascade Circuit



# Cascode Circuit

